VS-ST1200C..K Series

Vishay Semiconductors

Phase Control Thyristors (Hockey PUK Version), 1650 A



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K-PUK (A-24)

FEATURES

- Center amplifying gate
- Metal case with ceramic insulator
- International standard case K-PUK (A-24)
- High profile hockey PUK
- Designed and qualified for industrial level
- Material categorization: for definitions of compliance please see <u>www.vishay.com/doc?99912</u>

TYPICAL APPLICATIONS

- DC motor controls
- Controlled DC power supplies
- AC controllers

PRIMARY CHARACTERISTICS						
I _{T(AV)} 1650 A						
V _{DRM} /V _{RRM}	1200 V, 1400 V, 1600 V, 1800 V, 2000 V					
V _{TM}	1.73 V					
I _{GT}	100 mA					
TJ	-40 °C to +125 °C					
Package	K-PUK (A-24)					
Circuit configuration	Single SCR					

MAJOR RATINGS AND CHARACTERISTICS								
PARAMETER	TEST CONDITIONS	VALUES	UNITS					
1		1650	A					
I _{T(AV)}	T _{hs}	55	°C					
1		3080	A					
I _{T(RMS)}	T _{hs}	25	°C					
1	50 Hz	30 500	•					
ITSM 60 Hz		32 000	A					
l ² t	50 Hz	4651	kA ² s					
1-1	60 Hz	4250	KA-S					
V _{DRM} /V _{RRM}		1200 to 2000	V					
tq	Typical	200	μs					
TJ		-40 to +125	°C					

ELECTRICAL SPECIFICATIONS

VOLTAGE RA	VOLTAGE RATINGS									
TYPE NUMBER	VOLTAGE CODE	V _{DRM} /V _{RRM} , MAXIMUM REPETITIVE PEAK AND OFF-STATE VOLTAGE V	V _{RSM} , MAXIMUM NON-REPETITIVE PEAK VOLTAGE V	I_{DRM}/I_{RRM} MAXIMUM AT T _J = T _J MAXIMUM mA						
	12	1200	1300							
	14	1400	1500							
VS-ST1200CK	16	1600	1700	100						
18		1800	1900							
	20	2000	2100							

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ABSOLUTE MAXIMUM RATING	5					
PARAMETER	SYMBOL		TEST CON	IDITIONS	VALUES	UNITS
Maximum average on-state current	L	180° conduction, half sine wave		1650 (700)	А	
at heatsink temperature	I _{T(AV)}	double side	(single side) co	oled	55 (85)	°C
Maximum RMS on-state current	I _{T(RMS)}	DC at 25 °C	heatsink temp	erature double side cooled	3080	
		t = 10 ms	No voltage		30 500	
Maximum peak, one-cycle		t = 8.3 ms	reapplied		32 000	A kA ² s
non-repetitive surge current	ITSM	t = 10 ms	100 % V _{BBM}	Sinusoidal half wave, initial T _J = T _J maximum	25 700	
		t = 8.3 ms	reapplied		26 900	
Man .:		t = 10 ms	No voltage reapplied		4651	
	l ² t	t = 8.3 ms			4250	
Maximum I ² t for fusing	1-1	t = 10 ms	100 % V _{RBM}		3300	
		t = 8.3 ms	reapplied		3000	
Maximum I ² √t for fusing	l²√t	t = 0.1 ms t	o 10 ms, no volt	age reapplied	46 510	kA²√s
Low level value of threshold voltage	V _{T(TO)1}	(16.7 % x π	$x \ I_{T(AV)} < I < \pi \ x$	$I_{T(AV)}$), $T_J = T_J$ maximum	0.91	v
High level value of threshold voltage	V _{T(TO)2}	$(I > \pi x I_{T(AV)}), T_J = T_J maximum$			1.01	v
Low level value of on-state slope resistance	r _{t1}	(16.7 % x π x $I_{T(AV)} < I < \pi$ x $I_{T(AV)}$), $T_J = T_J$ maximum			0.21	mΩ
High level value of on-state slope resistance	r _{t2}	$(I > \pi \times I_{T(AV)}), T_J = T_J maximum$			0.19	1115.2
Maximum on-state voltage	V _{TM}	$I_{pk} = 4000 \text{ A}, T_J = T_J \text{ maximum, } t_p = 10 \text{ ms sine pulse}$			1.73	V
Maximum holding current	Ι _Η	T _ 25 °C	anada ayanlıy 1	2.V. registive load	600	m۸
Typical latching current	١L	$1_{\rm J} = 25$ C,	anoue supply 1	2 V resistive load	1000	mA

SWITCHING				
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS
Maximum non-repetitive rate of rise of turned-on current	dl/dt	Gate drive 20 V, 20 $\Omega,t_r \le 1~\mu s$ T_J = T_J maximum, anode voltage $\le 80~\%~V_{DRM}$	1000	A/µs
Typical delay time	t _d	Gate current 1 A, dl _g /dt = 1 A/ μ s V _d = 0.67 % V _{DRM} , T _J = 25 °C	1.9	
Typical turn-off time	tq	I_{TM} = 550 A, T_J = T_J maximum, dl/dt = 40 A/µs, V_R = 50 V, dV/dt = 20 V/µs, gate 0 V 100 $\Omega,$ t_p = 500 µs	200	μs

BLOCKING				
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS
Maximum critical rate of rise of off-state voltage	dV/dt	$T_J = T_J$ maximum linear to 80 % rated V_{DRM}	500	V/µs
Maximum peak reverse and off-state leakage current	I _{RRM} , I _{DRM}	$T_J = T_J$ maximum, rated V_{DRM}/V_{RRM} applied	100	mA





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TRIGGERING								
DADAMETED	SYMPOL	те	TEST CONDITIONS					
PARAMETER	SYMBOL					UNITS		
Maximum peak gate power	P _{GM}	$T_J = T_J$ maximum,	t _p ≤ 5 ms	1	6	w		
Maximum average gate power	P _{G(AV)}	T _J = T _J maximum,	f = 50 Hz, d% = 50	;	3	vv		
Maximum peak positive gate current	I _{GM}			3	.0	Α		
Maximum peak positive gate voltage	+ V _{GM}	$T_J = T_J maximum,$	$T_J = T_J$ maximum, $t_p \le 5$ ms 20			V		
Maximum peak negative gate voltage	- V _{GM}			5.0		v		
	I _{GT}	$T_J = -40 \ ^\circ C$		200	-	mA		
DC gate current required to trigger		T _J = 25 °C	Maximum required gate trigger/	100	200			
		T _J = 125 °C	current/voltage are the lowest	50	-			
		T _J = -40 °C	value which will trigger all units	1.4	-			
DC gate voltage required to trigger	V _{GT}	T _J = 25 °C	12 V anode to cathode applied	1.1	3.0	V		
		T _J = 125 °C		0.9	-	1		
DC gate current not to trigger	I _{GD}		Maximum gate current/voltage	10		mA		
DC gate voltage not to trigger	V _{GD}	$T_J = T_J maximum$	not to trigger is the maximum value which will not trigger any unit with rated V _{DRM} anode to cathode applied	0.25		V		

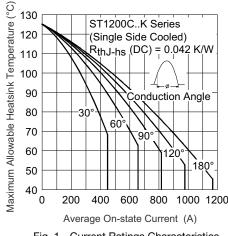
THERMAL AND MECHANICAL SPECIFICATIONS						
PARAMETER	SYMBOL	SYMBOL TEST CONDITIONS		UNITS		
Maximum operating junction temperature range	TJ		-40 to 125	°C		
Maximum storage temperature range	T _{Stg}		-40 to 150			
Maximum thermal resistance,	Б	DC operation single side cooled	0.0.42	K/W		
junction to heatsink	R _{thJ-hs}	DC operation double side cooled	0.021			
Maximum thermal resistance,		DC operation single side cooled	0.006			
case to heatsink	R _{thC-hs}	DC operation double side cooled	0.003			
Mounting force, ± 10 %			24 500 (2500)	N (kg)		
Approximate weight			425	g		
Case style		See dimensions - link at the end of datasheet	K-PUK	(A-24)		

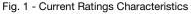
CONDUCTION ANGLE	SINUSOIDAL CONDUCTION		RECTANGULAR	R CONDUCTION	TEST CONDITIONS	UNITS		
CONDUCTION ANGLE	SINGLE SIDE	DOUBLE SIDE	SINGLE SIDE	DOUBLE SIDE	TEST CONDITIONS	UNITS		
180°	0.003	0.003	0.002	0.002				
120°	0.004	0.004	0.004	0.004				
90°	0.005	0.005	0.005	0.005	$T_J = T_J maximum$	K/W		
60°	0.007	0.007	0.007	0.007				
30°	0.012	0.012	0.012	0.012				

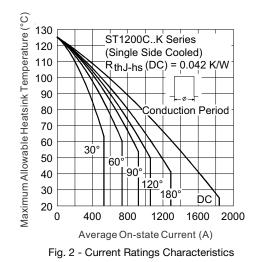
Note

• The table above shows the increment of thermal resistance R_{thJC} when devices operate at different conduction angles than DC





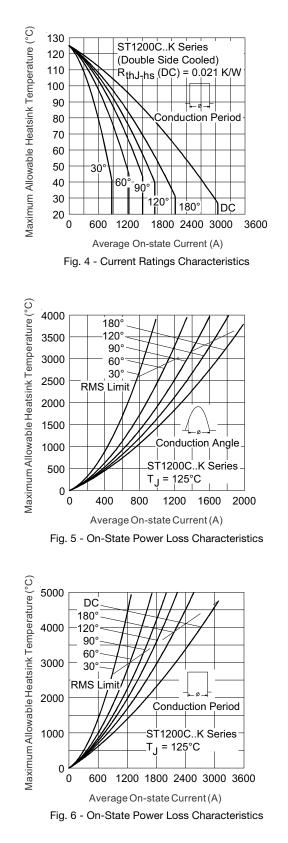




Maximum Allowable Heatsink Temperature (°C) ST1200C. K Series (Double Side Cooled) thJ-hs(DC) = 0.021 K/W Conduction Angle

Average On-state Current (A) Fig. 3 - Current Ratings Characteristics

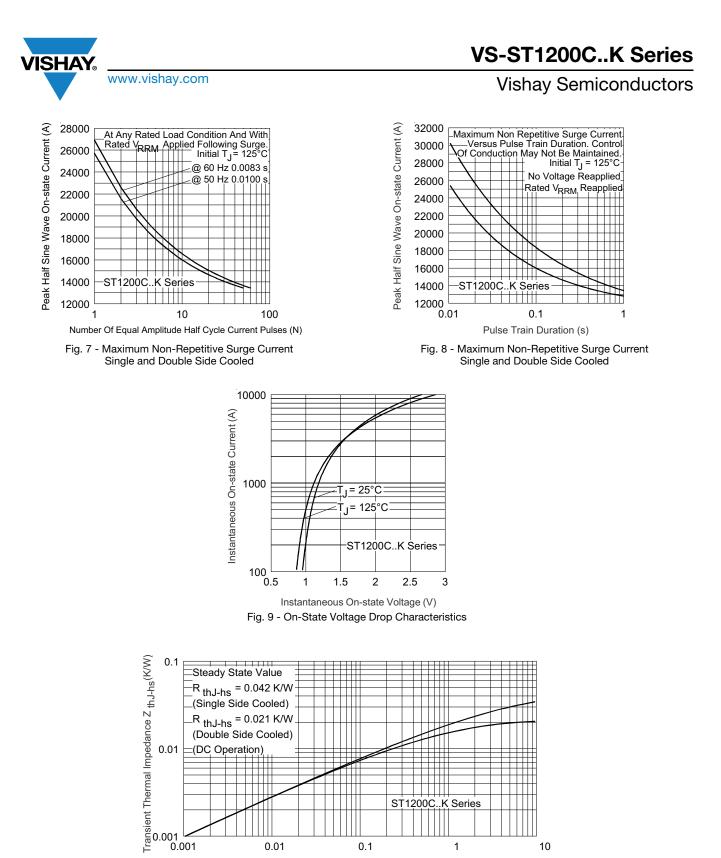
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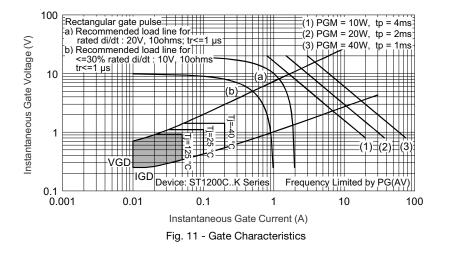


Square Wave Pulse Duration (s)

Fig. 10 - Thermal Impedance ZthJ-hs Characteristics

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ORDERING INFORMATION TABLE

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SHA

Device code	VS-	ST	120	0	С	20	к	1	-
	1	2	3	4	5	6	(7)	8	9
	1	- Visl	nay Sen	nicondu	ctors pr	oduct			
	2	- Thy	ristor						
	3	- Ess	ential p	art numl	ber				
	4	- 0 =	conver	ter grade	Э				
	5	- C =	cerami	c PUK					
	6	- Vol	tage co	de: code	e x 100	= V _{RRM}	(see Vo	Itage Ra	atings ta
	7	- K=	PUK ca	ase K-Pl	JK (A-2	4)			
	8	- 0 =	eyelet t	erminals	s (gate a	and aux	iliary ca	thode u	Insolder
	9			termina dt:• No	.0		,		unsolde tion)
				• L =	1000 V	/µs (spe	ecial sel	ection)	

LINKS TO RELATED DOCUMENTS					
Dimensions	www.vishay.com/doc?95081				

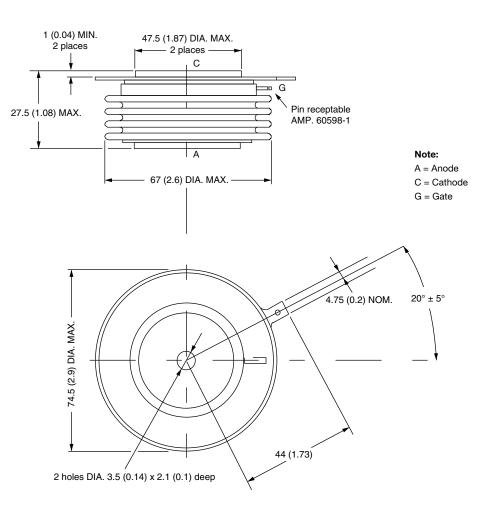


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K-PUK (A-24)

DIMENSIONS in millimeters (inches)

Creepage distance: 28.88 (1.137) minimum Strike distance: 17.99 (0.708) minimum



Quote between upper and lower pole pieces has to be considered after application of mounting force (see thermal and mechanical specification)



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